





Description:

MLCC consists of a conducting material and electrodes. To manufacture a chip-type SMT and achieve miniaturization, high density and high efficiency, ceramic condensers are used. The MLCC is made by NP0, X7R, X6S, X5R and Y5V dielectric material and which provides product with high electrical precision, stability and reliability.

Features:

- A wide selection of sizes is available (0201 to 1812).
- · High capacitance in given case size.
- · Capacitor with lead-free termination (pure Tin).

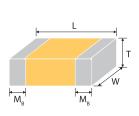
Applications:

- · For general digital circuit.
- · For power supply bypass capacitors.
- · For consumer electronics.
- · For telecommunication.

How To Order:

МС	1206	В	104	K	500	С	Т
IVIC	<u>Size</u>	Dielectric	<u>Capacitance</u>	<u>Tolerance</u>	Rated Voltage	<u>Termination</u>	Packaging style
Multicomp	Inch (mm) 0201 (0603) 0402 (1005) 0603 (1608) 0805 (2012) 1206 (3216) 1210 (3225) 1812 (4532)	N=NP0 (C0G) B=X7R F=Y5V X=X5R S=X6S	Two significant digits followed by no. of zeros. And R is in place of decimal point. Eg.: 0R5=0.5pF 1R0=1.0pF 104 = 10×10 ⁴ = 100nF	A=±0.05pF B=±0.1pF C=±0.25pF D=±0.5pF F=±1% G=±2% J=±5% K=±10% M=±20% Z=-20/+80%	Two significant digits followed by no. of zeros. And R is in place of decimal point. 4R0=4V DC 6R3=6.3V DC 100=10V DC 160=16V DC 250=25V DC 500=50V DC 101=100V DC	C=Cu/Ni/Sn	T=7" reeled R=7" reeled (2mm pitch for 0603 size; paper tape) G=13" reeled

External Dimensions:



The outline of MLCC

Size Inch (mm)	L (mm)	W (mm)	T (mm)/Symbo	ol	Soldering Method *	M _B (mm)
01R5 (0402)	0.4 ±0.02	0.2 ±0.02	0.2 ±0.02	V	R	0.1 ±0.03
0201 (0603)	0.6±0.03	0.3 ±0.03	0.3 ±0.03			0.15 +0.05
	0.6±0.05 ^{#2}	0.3 ±0.05 ^{#2}	0.3 ±0.05 ^{#2}	L	R	0.15 ±0.05
(0000)	0.6±0.09 ^{#3}	0.3 ±0.09 ^{#3}	0.3 ±0.09 ^{#3}			0.15 +0.1/-0.05
	1 ±0.05	0.5 ±0.05	0.5 ±0.05	N		
0402 (1005)	1 ±0.05	0.5 ±0.05	0.5 +0.02/-0.05	Q	R	0.25 +0.05/-0.1
	1 ±0.2	0.5 ±0.2	0.5 ±0.2	Е		10.00/ 0.1





Size Inch (mm)	L (mm)	W (mm)	T (mm)/Symb	ol	Soldering Method *	M _B (mm)
	1.6 ±0.1	0.8 ±0.1	0.8 ±0.07	S	R/W	
0603	1.6 +0.15/-	0.8 +0.15/-0.1	0.5 ±0.1	Н	R/W	0.4 ±0.15
(1608)	0.1	0.6 +0.15/-0.1	0.8 +0.15/-0.1	X	R/W	0.4 ±0.13
	1.6 ±0.2* ¹	0.8 ±0.2* ¹	0.8 ±0.2* ¹	<u> </u>	IX / VV	
			0.5 ±0.1	Н	R/W	
	2 ±0.15	1.25 ±0.1	0.6 ±0.1	Α	R/W	
0805	2 ±0.13	1.25 ±0.1	0.8 ±0.1	В	R/W	0.5 ±0.2
(2012)			1.25 ±0.1	D	R	0.5 ±0.2
	2 10 2	1.25 +0.2	0.85 ±0.1	Т	R/W	
	2 ±0.2	1.25 ±0.2	1.25 ±0.2	I	R	
			0.8 ±0.1	В	R/W	
	3.2 ±0.15	1.6 ±0.15	0.95 ±0.1	С	R	
		1.0 ±0.15	1.25 ±0.1	D	R	
1206 (3216)			1.15 ±0.15	J	R	0.6 ±0.2 (0.5±0.25)***
(3210)	3.2 ±0.2	10.00	1.6 ±0.2	G	R	(0.010.20)
		1.6 ±0.2	0.85 ±0.1	Т	R/W	
	3.2 +0.3/-0.1	1.6 +0.30/-0.1	1.6 +0.3/-0.1	Р	R	
			0.95 ±0.1	С	R	
	3.2 ±0.3	2.5±0.2	0.85 ±0.1	Т	R	
1210			1.25 ±0.1	D	R	0.75 ±0.25
(3225)			1.6 ±0.2	G	R	0.75 ±0.25
	3.2±0.4	2.5±0.3	2 ±0.2	K	R	
			2.5 ±0.3	М	R	
			1.25 ±0.1	D	R	
1808	4.5 ±0.4	2.02.10.25	1.4 ±0.15	F	R	0.75 ±0.25
(4520)	(4.5+0.5/- 0.3)**	2.03 ±0.25	1.6 ±0.2	G	R	(0.5±0.25)***
	313,		2 ±0.2	K	R	
			1.25 ±0.1	D	R	
	4.5 ±0.4	3.2 ±0.3	1.6 ±0.2	G	R	
1812 (4532)	4.5+0.5/-		2 ±0.2	K	R	0.75 ±0.25 0.5±0.25)***
(7002)	0.3)**	22.04	2.5 ±0.3	М	R	0.0±0.20)
		3.2 ±0.4	2.8 ±0.3	U	R	

^{*} R = Reflow soldering process; W = Wave soldering process.



^{**} For 1808_200V ~3kV, 1812_200V~3kV and safety certificated products.

^{***} For 1206_1000V ~3kV, 1808_200V ~3kV, 1812_200V~3kV and safety certificated products.

^{#1:} For 0603/Cap \geq 10 μ F or 0603(>10V)/Cap>1 μ F products.

^{#2:} For 0201/Cap≧0.68µF products.

^{#3:} For 0201/Cap >1µF products.



General Electrical Data:

Dielectric	NP0	X7R	Y5V	X5R	X6S					
Size		0402, 060	3, 0805, 1206, 121	0, 1812						
Capacitance range*	0.1pF to 0.1μF	100pF to 47μF	0.01μF to 100μF	100pF to 220μF	0.1μF to 100μF					
Capacitance tolerance**	Cap≤5pF#1: A (±0.05pF), B (±0.1pF), C (±0.25pF) 5pF <cap<10pf: (±0.25pf),="" (±0.5pf)="" (±1%),="" (±10%)<="" (±2%),="" (±5%),="" c="" cap≥10pf:="" d="" f="" g="" j="" k="" th=""><th>J (±5%), K (±10%), M (±20%)</th><th>M (±20%), Z (-20/+80%)</th><th>K (±10%), M (±20%)</th><th>K (±10%), M (±20%)</th></cap<10pf:>	J (±5%), K (±10%), M (±20%)	M (±20%), Z (-20/+80%)	K (±10%), M (±20%)	K (±10%), M (±20%)					
Rated voltage (WVDC)	10V, 16V, 25V, 50V,100V	6.3V, 10V, 16V,	25V, 50V, 100V	4V, 6.3V, 10V,	16V, 25V, 50V					
DF(Tan δ)*	Cap<30pF: Q≥400+20C Cap≥30pF: Q≥1000		N	Note 1						
Operating temperature	-55 to +12	5°C	-25°C to +85°C	-55°C to +85°C	-55°C to +105°C					
Capacitance characteristic	±30ppm	±15%	+30/-80%	±15%	±22%					
Termination		Ni/Sn (lead-free termination)								

#1: NP0, 0.1pF product only provide B tolerance

NP0: Apply 1.0±0.2Vrms, 1.0MHz±10% for Cap≤1000pF and 1.0±0.2Vrms, 1.0kHz±10% for Cap>1000pF, 25°C at ambient temperature

X7R/X6S/X5R: Apply 1.0±0.2Vrms, 1.0kHz±10%, at 25°C ambient temperature.

Y5V: Apply 1.0±0.2Vrms, 1.0kHz±10%, at 20°C ambient temperature.



^{*} Measured at the condition of 30~70% related humidity.

^{**} Preconditioning for Class II MLCC: Perform a heat treatment at 150±10°C for 1 hour, then leave in ambient condition for 24±2 hours before measurement.



Note 1:

X7R/X5R/X6S

Rated Vol.	D.F. ≦		Exception of D.F.≦
≧100V	≦2.5%	≦3%	1206≧0.47µF
= 100V	=2.5%	≦5%	0805>0.1μF, 0603≧0.068μF, 1206>1μF; TT series
		≦3%	0201(50V); 0603≧0.047μF; 0805≧0.18μF;1206≧0.47μF
50V	≦2.5%	≦5%	1210≧4.7µF
	-2.576	≦10%	0402 \ge 0.1 µF;0603 \ge 1 µF;0805 \ge 1 µF;1206 \ge 2.2 µF; 1210 \ge 10 µF;TT series
35V	≦3.5%	≦10%	0603≧1μF;0805≥2.2μF; 1210≧10μF
		≦5%	0201≥0.01μF;0805≥1μF;1210≥10μF
		≦7%	0603≧0.33μF; 1206≧4.7μF
25V	≦3.5%	≦10%	0402≧0.10μF;0603≧0.47μF; 0805≧2.2μF; 1206≧6.8μF ; 1210≧22μF ; TT series
		≦12.5%	0402≧1µF
16V	≦3.5%	≦5%	0201≥0.01µF;0402≥0.033µF; 0603≥0.15µF; 0805≥0.68µ 1206≥2.2µF;1210≥4.7µF
160	=3.5%	≦10%	0201≥0.1μF;0402≥ 0.22uF; 0603≥0.68μF;0805≥2.2μF; 1206≥4.7μF; 1210≥22μF; TT series
10V	≦5%	≦10%	0201 \ge 0.012µF;0402 \ge 0.33µF(0402/X7R \ge 0.22µF); TT series 0603 \ge 0.33µF; 0805 \ge 2.2µF;1206 \ge 2.2µF;1210 \ge 22µF
		≦15%	0201≧0.1μF; 0402≧1μF
6.3V	≦10%	≦15%	0201≥0.1μF;0402≥1μF;0603≥10μF; 0805≥4.7μF; 1206≥47μF:1210≥100μF; TT series
		≦20%	0402≧2.2μF
4V	≦15%		

Y5V

Rated vol.	D.F.≦		Exception of D.F.≦
≧50V	5%	7%	0603 ≥ 0.1μF; 0805 ≥ 0.47μF; 1206 ≥ 4.7μF
35V	7%		
25V	5%	7%	0402 \ge 0.047µF;0603 \ge 0.1µF; 0805 \ge 0.33µF;1206 \ge 1µF; 1210 \ge 4.7µF
20 0		9%	$0402 \ge 0.068 \mu F; 0603 \ge 0.47 \mu F; 1206 \ge 4.7 \mu F; 1210 \ge 22 \mu F$
16V (C<1.0µF)	7%	9%	0402≧0.068μF; 0603≧0.68μF
16ν (С<1.0με)	1 70	12.5%	0402≧0.22µF
16V (C≧1.0µF)	9%	12.5%	0603≥2.2μF; 0805≥3.3μF; 1206≥10μF; 1210≥22μF; 1812≥47μF
10V	12.5%	20%	0402≧0.47μF
6.3V	20%		

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Capacitance Range

NP0 Dielectric 0201, 0402, 0603, 0805 Sizes

	Dielectric									NI	P0								
	Size		0201				0402		1			0603					0805		
F	Rated Voltage (V DC)	16	25	50	10	16	25	50	100	10	16	25	50	100	10	16	25	50	100
	0.1pF (0R1)	L	L	L	N	N	N	N											
	0.2pF (0R2)	L	L	L	N	N	N	N											
	0.3pF (0R3)	L	L	L	N	N	N	N											
	0.4pF (0R4)	L	L	L	N	N	N	N											
	0.5pF (0R5)	L	L	L	N	N	N	N	N	S	S	s	S	S	Α	А	Α	А	А
	0.6pF (0R6)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	Α	А	Α
	0.7pF (0R7)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	А	Α
	0.8pF (0R8)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	А	Α
	0.9pF (0R9)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	Α	А	Α
	1.0pF (1R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	Α	Α	Α
	1.2pF (1R2)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	Α	А	Α
	1.5pF (1R5)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	Α	А	Α
	1.8pF (1R8)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	Α	А	Α
	2.0pF (2R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	Α	Α	Α
	2.2pF (2R2)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	2.7pF (2R7)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	3.0pF (3R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
ø	3.3pF (3R3)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
Capacitance	3.9pF (3R9)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
acit	4.0pF (4R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	Α	Α	Α
аря	4.7pF (4R7)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	Α	Α	Α
O	5.0pF (5R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	5.6pF (5R6)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	6.0pF (6R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	6.8pF (6R8)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	7.0pF (7R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	8.0pF (8R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	8.2pF (8R2)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	9.0pF (9R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	10pF (100)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	12pF (120)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	15pF (150)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	18pF (180)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	22pF (220)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	27pF (270)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	33pF (330)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	39pF (390)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	47pF (470)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	56pF (560)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	Α	Α	Α







	Dielectric	Ι								NI	P0								
	Size	İ	0201				0402					0603					0805		
	Rated Voltage (V DC)	16	25	50	10	16	25	50	100	10	16	25	50	100	10	16	25	50	100
	68pF (680)	L	L	L	N	N	N	N	N	S	S	s	S	S	Α	А	Α	А	Α
	82pF (820)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	Α	А	Α
	100pF (101)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	Α	А	Α
	120pF (121)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	Α	А	Α
	150pF (151)				N	N	N	N	N	S	S	s	S	S	Α	А	Α	А	Α
	180pF (181)				N	N	N	N	N	S	S	s	S	S	Α	А	Α	А	Α
	220pF (221)				N	N	N	N	N	S	S	S	S	S	Α	А	Α	А	Α
	270pF (271)				N	N	N	N		S	S	S	S	S	Α	А	Α	А	Α
	330pF (331)				N	N	N	N		S	S	S	S	S	Α	А	Α	А	Α
	390pF (391)				N	N	N	N		S	S	S	S	S	В	В	В	В	В
	470pF (471)				N	N	N	N		S	S	S	S	S	В	В	В	В	В
	560pF (561)				N	N	N	N		S	S	S	S	S	В	В	В	В	В
	680pF (681)				N	N	N	N		S	S	S	S	S	В	В	В	В	В
Capacitance	820pF (821)				N	N	N	N		S	S	S	S	S	В	В	В	В	В
ita	1,000pF (102)				N	N	N	N		S	S	S	S	S	В	В	В	В	В
bac	1,200pF (122)									Х	Х	Х	Х	Х	В	В	В	В	В
Cal	1,500pF (152)									Х	Х	Х	Х	Х	В	В	В	В	В
	1,800pF (182)									Х	Х	Х	Х		В	В	В	В	В
	2,200pF (222)									Х	Х	Х	Х		В	В	В	В	В
	2,700pF (272)									Х	Х	Х	Х		D	D	D	D	D
	3,300pF (332)									Х	Х	Х	Х		D	D	D	D	D
	3,900pF (392)									Х	Х	Х	Х		D	D	D	D	D
	4,700pF (472)									Х	Х	Х	Х		D	D	D	D	D
	5,600pF (562)									Х	Х	Х	Х		D	D	D	D	D
	6,800pF (682)									Х	Х	Х	Х		D	D	D	D	D
	8,200pF (822)									Х	Х	Х	Х		D	D	D	D	
	0.010uF (103)									Х	Х	Х	Х		D	D	D	D	
	0.012uF (123)														Т	Т	Т	Т	
	0.018uF (183)														D	D	D	D	
	0.022uF (223)														D	D	D	D	

^{1.} The letter in cell is expressed the symbol of product thickness.

NP0 Dielectric 1206, 1210, 1812 Sizes

	Dielectric							NP0						
	Size			1206					1210				1812	
F	Rated Voltage (V DC)		16	25	50	100	10	16	25	50	100	16	50	100
ø	1.0pF (1R0)													
anc	1.2pF (1R2) 1.2pF (1R2) 1.5pF (1R5) 1.8pF (1R8)		В	В	В	В								
cit	1.5pF (1R5)		В	В	В	В								
ара	1.8pF (1R8)	В	В	В	В	В								
ပိ	2.2pF (2R2)	В	В	В	В	В								





	Dielectric							NP0						
	Size	İ		1206					1210				1812	
ı	Rated Voltage (V DC)	10	16	25	50	100	10	16	25	50	100	16	50	100
	2.7pF (2R7)	В	В	В	В	В								
	3.3pF (3R3)	В	В	В	В	В								
	3.9pF (3R9)	В	В	В	В	В								
	4.7pF (4R7)	В	В	В	В	В								
	5.6pF (5R6)	В	В	В	В	В								
	6.8pF (6R8)	В	В	В	В	В								
	8.2pF (8R2)	В	В	В	В	В								
	10pF (100)	В	В	В	В	В	С	С	С	С	С	D	D	D
	12pF (120)	В	В	В	В	В	С	С	С	С	С	D	D	D
	15pF (150)	В	В	В	В	В	С	С	С	С	С	D	D	D
	18pF (180)	В	В	В	В	В	С	С	С	С	С	D	D	D
	22pF (220)	В	В	В	В	В	С	С	С	С	С	D	D	D
	27pF (270)	В	В	В	В	В	С	С	С	С	С	D	D	D
	33pF (330)	В	В	В	В	В	С	С	С	С	С	D	D	D
	39pF (390)	В	В	В	В	В	С	С	С	С	С	D	D	D
	47pF (470)	В	В	В	В	В	С	С	С	С	С	D	D	D
	56pF (560)	В	В	В	В	В	С	С	С	С	С	D	D	D
	68pF (680)	В	В	В	В	В	С	С	С	С	С	D	D	D
	82pF (820)	В	В	В	В	В	С	С	С	С	С	D	D	D
ස	100pF (101)	В	В	В	В	В	С	С	С	С	С	D	D	D
Capacitance	120pF (121)	В	В	В	В	В	С	С	С	С	С	D	D	D
pac	150pF (151)	В	В	В	В	В	С	С	С	С	С	D	D	D
ပြိ	180pF (181)	В	В	В	В	В	С	С	С	С	С	D	D	D
	220pF (221)	В	В	В	В	В	С	С	С	С	С	D	D	D
	270pF (271)	В	В	В	В	В	С	С	С	С	С	D	D	D
	330pF (331)	В	В	В	В	В	С	С	С	С	С	D	D	D
	390pF (391)	В	В	В	В	В	С	С	С	С	С	D	D	D
	470pF (471)	В	В	В	В	В	С	С	С	С	С	D	D	D
	560pF (561)	В	В	В	В	В	С	С	С	С	С	D	D	D
	680pF (681)	В	В	В	В	В	С	С	С	С	С	D	D	D
	820pF (821)	В	В	В	В	В	С	С	С	С	С	D	D	D
	1,000pF (102)	В	В	В	В	В	С	С	С	С	С	D	D	D
	1,200pF (122)	В	В	В	В	В	С	С	С	С	С	D	D	D
	1,500pF (152)	В	В	В	В	В	С	С	С	С	С	D	D	D
	1,800pF (182)	В	В	В	В	В	С	С	С	С	С	D	D	D
	2,200pF (222)	В	В	В	В	В	С	С	С	С	С	D	D	D
	2,700pF (272)	В	В	В	В	В	С	С	С	С	С	D	D	D
	3,300pF (332)	В	В	В	В	В	С	С	С	С	С	D	D	D
	3,900pF (392)	В	В	В	В	В	С	С	С	С	С	D	D	D
	4,700pF (472)	В	В	В	В	В	С	С	С	С	С	D	D	D
	5,600pF (562)	В	В	В	В	В	С	С	С	С	С	D	D	D
	6,800pF (682)	С	С	С	С	С	С	С	С	С	С	D	D	D





	Dielectric							NP0						
	Size			1206					1210				1812	
F	Rated Voltage (V DC)	10	16	25	50	100	10	16	25	50	100	16	50	100
	8,200pF (822)	D	D	D	D	D	С	С	С	С	С	D	D	D
	0.010µF (103)	D	D	D	D	D	С	С	С	С	С	D	D	D
	0.012µF (123)	Т	Т	Т	Т	Т	D	D	D	D	D	D	D	D
	0.015µF (153)	Т	Т	Т	Т	Т	D	D	D	D	D	D	D	D
	0.018µF (183)	Т	Т	Т	Т	Т						D	D	D
ස	0.022µF (223)	Т	Т	Т	Т	Т						D	D	D
itan	0.022μF (223) 0.027μF (273) 0.033μF (333)		Т	Т	Т							D	D	D
pac	0.033µF (333)	Т	Т	Т	Т							D	D	D
ပြိ	0.039µF (393)	J	J	J	J									
	0.047µF (473)	J	J	J	J									
	0.056µF (563)	J	J	J	J									
	0.068µF (683)	G	G	G	G									
	0.082µF (823)	G	G	G	G									
	0.1µF (104)	G	G	G	G									

^{1.} The letter in cell is expressed the symbol of product thickness.

X7R Dielectric 0201, 0402, 0603, 0805 Sizes

	Dielectric		X7R																					
	Size			0201					04	02					06	03					08	05		
Ra	ated Voltage (V DC)	6.3	10	16	25	50	6.3	10	16	25	50	100	6.3	10	16	25	50	100	6.3	10	16	25	50	100
	100pF (101)			L	L	L		N	N	N	N	N		S	s	S	S	s		В	В	В	В	В
	120pF (121)			L	L	L		N	N	N	N	N		S	S	S	S	s		В	В	В	В	В
	150pF (151)			L	L	L		N	N	N	N	N		S	S	S	S	S		В	В	В	В	В
	180pF (181)			L	L	L		N	N	N	N	N		S	S	S	S	S		В	В	В	В	В
	220pF (221)			L	L	L		N	N	N	N	N		S	s	S	S	s		В	В	В	В	В
	270pF (271)			L	L	L		N	N	N	N	N		S	s	S	S	S		В	В	В	В	В
	330pF (331)			L	L	L		N	N	N	N	N		S	s	S	S	s		В	В	В	В	В
	390pF (391)			L	L	L		N	N	N	N	N		S	s	S	S	s		В	В	В	В	В
ස	470pF (471)			L	L	L		N	N	N	N	N		S	S	S	S	S		В	В	В	В	В
itan	560pF (561)			L	L	L		N	N	N	N	N		S	S	S	S	S		В	В	В	В	В
Capacitance	680pF (681)			L	L	L		N	N	N	N	N		S	S	S	S	S		В	В	В	В	В
ပိ	820pF (821)			L	L	L		N	N	N	N	N		S	S	S	S	S		В	В	В	В	В
	1,000pF (102)	L	L	L	L	L		N	N	N	N	N		S	S	S	S	S		В	В	В	В	В
	1,200pF (122)	L	L	L	L			N	N	N	N			S	S	S	S	s		В	В	В	В	В
	1,500pF (152)	L	L	L	L			N	N	N	N			S	S	S	S	s		В	В	В	В	В
	1,800pF (182)	L	L	L				N	N	N	N			S	S	S	S	S		В	В	В	В	В
	2,200pF (222)	L	L	L				N	N	N	N			S	S	S	S	S		В	В	В	В	В
	2,700pF (272)	L	L	L				N	N	N	N			S	S	S	S	S		В	В	В	В	В
	3,300pF (332)	L	L	L				N	N	N	N			S	S	S	S	s		В	В	В	В	В
	3,900pF (392)	L	L	L				N	N	N	N			S	s	S	S	S		В	В	В	В	В





	Dielectric												X7F	₹										
	Size			0201					04	02					06	03					08	05		
Ra	ted Voltage (V DC)	6.3	10	16	25	50	6.3	10	16	25	50	100	6.3	10	16	25	50	100	6.3	10	16	25	50	100
	4,700pF (472)	L	L	L				N	N	N	N			S	S	S	S	S		В	В	В	В	В
	5,600pF (562)	L	L					N	N	N	N			S	S	S	S	S		В	В	В	В	В
	6,800pF (682)	L	L					N	N	N	N			S	S	S	S	S		В	В	В	В	В
	8,200pF (822)	L	L					N	N	N	N			S	S	S	S	S		В	В	В	В	В
	0.010µF (103)	L	L	L				N	N	N	N			S	S	S	S	S		В	В	В	В	В
	0.012µF (123)							N	N	N				S	s	S	S	Х		В	В	В	В	В
	0.015µF (153)							N	N	N				S	s	S	S	Х		В	В	В	В	В
	0.018µF (183)							N	N	N				S	S	S	S	Х		В	В	В	В	В
	0.022µF (223)							N	N	N	N			S	S	S	S	Х		В	В	В	В	В
	0.027µF (273)							N	N	N				S	S	S	S	Х		В	В	В	В	D
	0.033µF (333)							N	N	N	N			S	s	S	Х	Х		В	В	В	В	D
	0.039µF (393)							N	N	N				S	s	S	Х	Х		В	В	В	В	D
	0.047µF (473)							N	N	N	N			S	S	S	Х	Х		В	В	В	В	D
	0.056µF (563)							N	N					S	S	S	Х	Х		В	В	В	В	D
	0.068µF (683)							N	N		N			S	S	S	Х	Х		В	В	В	В	D
	0.082µF (823)							N	N					S	S	S	Х	Х		В	В	В	В	D
_ გ	0.10µF (104)						N	N	N	N	N			S	S	S	Х	Х		В	В	В	В	D
itan	0.12µF (124)													S	S	Х				В	В	В	D	
Capacitance	0.15µF (154)													S	S	Х				D	D	D	D	
င္မ	0.18µF (184)													S	S	Х				D	D	D	D	
	0.22µF (224)						N	N	N	N				S	S	Х	Х			D	D	D	D	Т
	0.27µF (274)												Х	Х	Х	Х				D	D	D	ı	
	0.33µF (334)												Х	Х	Х	Х				D	D	D	ı	
	0.39µF (394)												Х	Х	Х	Х				D	D	D	ı	
	0.47µF (474)						N	N					Х	Х	Х	Х	Х			D	D	D	ı	1
	0.56µF (564)												Х	Х	Х					D	D	D		
	0.68µF (684)												Х	Х	Х					D	D	D		
	0.82µF (824)												Х	Х	Х					D	D	D		
	1.0µF (105)						N						Х	Х	Х	Х	Х			D	D	D	ı	
	1.5µF (155)																			I	ı	ı		
	2.2µF (225)												Х	Х					I	I	ı	ı	ı	
	3.3µF (335)																							
	4.7µF (475)																		ı	ı	ı	ı		
	6.8µF (685)																					Ì		
	10μF (106)																		ı	ı	l*			
	22µF (226)																							

- 1. The letter in cell is expressed the symbol of product thickness.
- 2. The letter in cell with " * " mark is expressed product not in 10% (code "K") tolerance.





X7R Dielectric 1206, 1210, 1812 Sizes

	Dielectric									X7R								
	Size			12	06					12	10					1812		
Ra	ted Voltage (V DC)	6.3	10	16	25	50	100	6.3	10	16	25	50	100	10	16	25	50	100
	100pF (101)																	
	120pF (121)																	
	150pF (151)		В	В	В	В	В											
	180pF (181)		В	В	В	В	В											
	220pF (221)		В	В	В	В	В											
	270pF (271)		В	В	В	В	В											
	330pF (331)		В	В	В	В	В											
	390pF (391)		В	В	В	В	В											
	470pF (471)		В	В	В	В	В											
	560pF (561)		В	В	В	В	В											
	680pF (681)		В	В	В	В	В											
	820pF (821)		В	В	В	В	В											
	1,000pF (102)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	1,200pF (122)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	1,500pF (152)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	1,800pF (182)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	2,200pF (222)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	2,700pF (272)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
Capacitance	3,300pF (332)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
acit	3,900pF (392)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
Сар	4,700pF (472)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	5,600pF (562)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	6,800pF (682)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	8,200pF (822)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.010µF (103)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.012µF (123)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.015µF (153)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.018µF (183)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.022µF (223)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.027µF (273)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.033µF (333)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.039µF (393)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.047µF (473)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.056µF (563)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.068µF (683)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.082µF (823)		В	В	В	В	D		С	С	С	С	С	D	D	D	D	D
	0.10µF (104)		В	В	В	В	D		С	С	С	С	С	D	D	D	D	D
	0.12µF (124)		В	В	В	В	D		С	С	С	С	С	D	D	D	D	D
	0.15µF (154)		С	С	С	С	G		С	С	С	С	D	D	D	D	D	D



I	Dielectric									X7R								
	Size			12	:06					12	10					1812		
Ra	ited Voltage (V DC)	6.3	10	16	25	50	100	6.3	10	16	25	50	100	10	16	25	50	100
	0.18µF (184)		С	С	С	С	G		С	С	С	С	D	D	D	D	D	D
	0.22µF (224)		С	С	С	С	G		С	С	С	С	D	D	D	D	D	D
	0.27µF (274)		С	С	С	D	G		С	С	С	С	G	D	D	D	D	D
	0.33µF (334)		С	С	С	D	G		С	С	С	D	G	D	D	D	D	D
	0.39µF (394)		С	С	J	Р	G		С	С	С	D	М	D	D	D	D	D
	0.47µF (474)		J	J	J	Р	G		С	С	С	D	М	D	D	D	D	К
	0.56µF (564)		J	J	J	Р	Р		D	D	D	D	М	D	D	D	D	К
_	0.68µF (684)		J	J	J	Р	Р		D	D	D	D	K	D	D	D	К	К
Capacitance	0.82µF (824)		J	J	J	Р	Р		D	D	D	D	K	D	D	D	К	К
acita	1.0µF (105)		J	J	J	Р	Р		D	D	D	D	K	D	D	D	К	К
Сар	1.5µF (155)	J	J	J	Р					K	G	М	М					К
	2.2µF (225)	J	J	J	Р	Р	Р			K	G	М	М				М	М
	3.3µF (335)		Р	Р	Р					K	G							
	4.7µF (475)	Р	Р	Р	Р	Р			K	K	K	М						
	6.8µF (685)																	
	10µF (106)	Р	Р	Р	Р				К	K	K	М						
	22µF (226)	Р	Р	P*					М	М	М							
	47µF (476)							М	М									
ı	100µF (107)																	

^{1.} The letter in cell is expressed the symbol of product thickness.

Y5V Dielectric 0402, 0603, 0805 Sizes

	Dielectric			•	•			•	Y!	5V							
	Size			0402					0603					08	05		
Ra	ited Voltage (V DC)	6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50	100
	0.010µF (103)		N	N	N	N		S	S	S	S		Α	Α	Α	Α	В
	0.015µF (153)		N	N	N	N		S	S	S	S		Α	Α	Α	Α	В
	0.022µF (223)		N	N	N	N		S	S	S	S		Α	Α	Α	Α	В
	0.033µF (333)		N	N	N	N		S	S	S	S		Α	Α	Α	Α	В
	0.047µF (473)		N	N	N			S	S	S	S		Α	Α	Α	Α	В
8	0.068µF (683)		N	N	N			S	S	S	S		Α	Α	Α	Α	В
Capacitance	0.10µF (104)		N	N	N			S	S	S	S		Α	Α	Α	Α	В
bac	0.15µF (154)		N	N				S	S	S	S		Α	Α	Α	Α	
ပိ	0.22µF (224)	N	N	N				S	S	S	S		Α	А	Α	Α	
	0.33µF (334)	N	N	N				S	S	s	Х		В	В	В	В	
	0.47µF (474)	N	N	N				S	S	Х	Х		В	В	В	В	
	0.68µF (684)	N						S	Х	Х			В	В	D	D	
	1.0µF (105)	N	N					S	Х	Х			В	В	D	D	
	1.5µF (155)							S					D	D			



^{2.} The letter in cell with " * " mark is expressed product not in 10% (code "K") tolerance.



	Dielectric								Y!	5V							
	Size			0402					0603					08	05		
Ra	ited Voltage (V DC)	6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50	100
	2.2µF (225)						S	S	Х				D	D	ı		
ළ	3.3µF (335)												D	D			
Capacitance	4.7μF (475)						Х	Х					D	D	I		
pac	6.8µF (685)												I				
ပြီ	10µF (106)											I	I	I			
	22µF (226)											I	ı				

^{1.} The letter in cell is expressed the symbol of product thickness.

Y5V Dielectric 1206, 1210, 1812 Sizes

	Dielectric									Y5V								
	Size			12	06					1:	210					1812		
Ra	ted Voltage (V DC)	6.3	10	16	25	50	100	6.3	10	16	25	50	100	10	16	25	50	100
	0.010µF (103)		В	В	В	В	В						С					D
	0.015µF (153)		В	В	В	В	В						С					D
	0.022µF (223)		В	В	В	В	В						С					D
	0.033µF (333)		В	В	В	В	В						С					D
	0.047µF (473)		В	В	В	В	В						С					D
	0.068µF (683)		В	В	В	В	В						С					D
	0.10µF (104)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.15µF (154)		В	В	В	В	С		С	С	С	С	С	D	D	D	D	D
	0.22µF (224)		В	В	В	В	С		С	С	С	С	С	D	D	D	D	D
ස	0.33µF (334)		В	В	В	В			С	С	С	С	С	D	D	D	D	D
itan	0.47µF (474)		В	В	В	В			С	С	С	С		D	D	D	D	D
Capacitance	0.68µF (684)		В	В	В	В			С	С	С	С		D	D	D	D	D
ပြိ	1.0µF (105)		С	С	С	С			С	С	С	С		D	D	D	D	D
	1.5µF (155)		С	С	С				С	С	С			D	D	D	D	
	2.2µF (225)		С	С	С	J			С	С	С	G		D	D	D	D	
	3.3µF (335)		J	J	J				С	С	С			D	D	D	D	
	4.7µF (475)		J	J	J	Р			С	С	D	G		D	D	D	D	
	6.8µF (685)		J	J					С	С	D			D	D	D	D	
	10μF (106)		J	J	Р				D	D	G			D	D	D	K	
	22µF (226)		Р	Р					К	К								
	47µF (476)	Р						К	К						М			
	100μF (107)							М										

^{1.} The letter in cell is expressed the symbol of product thickness.



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X5R Dielectric 0201, 0402, 0603, 0805, 1206, 1210 Sizes

	Dielectric								X5R							
	Size			0201					0402					0603		
Rated	l Voltage (V DC)	6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50
	100pF (101)			L	L	L										
	120pF (121)			L	L	L										
	150pF (151)			L	L	L										
	180pF (181)			L	L	L										
	220pF (221)			L	L	L										
	270pF (271)			L	L	L										
	330pF (331)			L	L	L										
	390pF (391)			L	L	L										
	470pF (471)			L	L	L										
	560pF (561)			L	L	L										
	680pF (681)			L	L	L										
	820pF (821)			L	L	L										
	1,000pF (102)		L	L	L	L										
	1,500pF (152)		L	L												
	2,200pF (222)		L	L												
	2,700pF (272)		L	L												
	3,300pF (332)		L	L												
	4,700pF (472)		L	L												
	6,800pF (682)		L													
e	0.010µF (103)	L	L	L	L											
Capacitance	0.015µF (153)	L	L													
ıpac	0.022µF (223)	L	L													
ပ္ပ	0.027µF (273)	L	L						N							
	0.033µF (333)	L	L						N							
	0.039µF (393)	L	L						N							
	0.047µF (473)	L	L						N							
	0.056µF (563)	L	L					N	N							
	0.068µF (683)	L	L					N	N							
	0.082µF (823)	L	L				N	N	N							
	0.10µF (104)	L	L	L	L		N	N	N	N	N					
	0.15µF (154)						N	N	N	N						
	0.22µF (224)	L	L				N	N	N	N	N			Х	Х	
	0.27uF (274)												Х	Х	Х	
	0.33µF (334)						N	N				Х	Х	Х	Х	
	0.39µF (394)												Х	Х	Х	
	0.47µF (474)	L					N	N	Е	Е	Е	Х	Х	Х	Х	X
	0.68µF (684)						N	N				Х	Х	Х	Х	
	0.82uF (824)											Х	Х	Х		
	1.0µF (105)	L	L*				N	N	N	N		Х	Х	Х		>
	1.5µF (155)											Х				
	2.2µF (225)	L*					N	N	E*	Е		Х	Х	Х	Х	X
	3.3µF (335)		Ì		Ì							Х	Х	ĺ	ĺ	Г





ı	Dielectric								X5R							
	Size			0201					0402					0603		
Rated	Voltage (V DC)	6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50
9	4.7µF (475)						E*	E*				Х	Х	Х	Х	
Capacitance	6.8uF (685)															
pac	10μF (106)						E*	E*				Х	Х	Х	X*	
ပိ	22µF (226)											X*	X*			

	Dielectric									X5R								
	Size			12	06					1210					18	12		
Rate	d Voltage (V DC)	4	6.3	10	16	25	50	6.3	10	16	25	50	4	6.3	10	16	25	50
	1.0µF (105)			D	D	D	-1											
	1.5µF (155)		ı	I	ı	I			J	J					K	К		
	2.2µF (225)		ı	I	ı	I	I		J	J	Р	Р			K	К		
	3.3µF (335)		ı	ı	ı	ı			Р	Р	Р							
Capacitance	4.7µF (475)		ı	ı	ı	ı	ı	Р	Р	Р	Р	Р			K	К	К	
acits	6.8uF (685)							Р	Р									
Cap	10µF (106)		ı	ı	ı	ı	ı	Р	Р	Р	Р	Р		K	K	К	К	М
	22µF (226)		l*	l*	l*			Р	Р	Р	Р			М	М	М	М	
	47µF (476)		l*	l*				Р	Р					М	М	М		
	100μF (107)	l*						P*						M*	М*			
	220µF (227)												M*					

^{1.} The letter in cell is expressed the symbol of product thickness.

X6S Dielectric 0201, 0402, 0603, 0805, 1206, 1210 Sizes

	Dielectric														X6S													
	Size	02	201		04	02				0603					08	05					1206					1210		
Rate	ed Voltage (V DC)	4	6.3	6.3	10	16	25	4	6.3	10	16	25	4	6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50
	0.10µF (104)	L	L																									
	0.15µF (154)																											
	0.22µF (224)		L																									
	0.33µF (334)																											
	0.47µF (474)			N																								
	0.68µF (684)																											
, e	1.0µF (105)	L*		N	Е	Е	Е																					
Capacitance	1.5µF (155)																											
арас	2.2µF (225)			N	Е	Е						Х																
۳	3.3µF (335)																											
ĺ	4.7µF (475)								Х		Х	Х					1	1										
ĺ	6.8uF (685)																											
	10μF (106)								X*	X*	X*		ı	1	I	1	ı					G						
	22μF (226)							X*	X*					l*	l*	l*				Р	P*						М	
	47μF (476)												l*						Р					М	М	М		
	100μF (107)																							M*				

^{1.} The letter in cell is expressed the symbol of product thickness.



^{2.} The letter in cell with " * " mark is expressed product not in 10% (code "K") tolerance.

^{2.} The letter in cell with " * " mark is expressed product not in 10% (code "K") tolerance.



Packaging Dimension And Quantity:

Sizo	Thickness (mm)/6	Symbol	Pape	r tape	Plasti	c tape
Size	Thickness (mm)/S	symbol	7" reel	13" reel	7" reel	13" reel
	0.3 ±0.03	L	15,000	70,000	-	-
0201 (0603)	0.3 ± 0.05	L	15,000	-	-	-
	0.3 ±0.09	L	15,000	-	-	-
	0.5 ±0.05	N	10,000	50,000	-	-
0402 (1005)	0.5 +0.02/-0.05	Q	10,000	50,000	-	-
	0.5 ±0.2	E	10,000	-	-	-
	0.5 ±0.1	Н	4,000	-	-	-
0603 (1608)	0.8 ±0.07	S	4,000	15,000	-	-
	0.8 +0.15/-0.1	Х	4,000	15,000	-	-
	0.5 ±0.1	Н	4,000	15,000	-	-
ĺ	0.6 ±0.1	А	4,000	15,000	-	-
0005 (0040)	0.8 ±0.1	В	4,000	15,000	-	-
0805 (2012)	0.85 ±0.1	Т	4,000	15,000	-	-
İ	1.25 ±0.1	D	-	-	3,000	10,000
Ī	1.25 ±0.2	ı	-	-	3,000	10,000
	0.8 ±0.1	В	4,000	15,000	-	-
Ī	0.85 ±0.1	Т	4,000	15,000	-	-
	0.95 ±0.1	С	-	-	3,000	10,000
1206 (3216)	1.15 ±0.15	J	-	-	3,000	10,000
	1.25 ±0.1	D	-	-	3,000	10,000
	1.6 ±0.2	G	-	-	2,000	10,000
	1.6 +0.30/-0.10	Р	-	-	2,000	9,000
	0.85 ±0.1	Т	-	-	3,000	10,000
	0.95 ±0.1	С	-	-	3,000	10,000
1210 (2225)	1.25 ±0.1	D	-	-	3,000	10,000
1210 (3225)	1.6 ±0.2	G	-	-	2,000	-
Ī	2 ±0.2	К	-	-	1,000	6,000
Ī	2.5 ±0.3	М	-	-	1,000	6,000
	1.25 ±0.1	D	-	-	2,000	10,000
1000 (4500)	1.1 ±0.15	F	-	-	2,000	10,000
1808 (4520)	1.6 ±0.2	G	-	-	2,000	8,000
	2 ±0.2	К	-	-	1,000	6,000
	1.25 ±0.1	D	-	-	1,000	5,000
İ	1.6 ±0.2	G	-	-	1,000	-
1812 (4532)	2 ±0.2	К	-	-	1,000	-
Ī	2.5 ±0.3	М	-	-	500	3,000
Ī	2.8 ±0.3	U	-	-	500	-

Unit: pieces

Reliability Test Conditions And Requirements:

No	Item	Test Condition	Requirements
1	Visual and Mechanical	-	No remarkable defect. Dimensions to conForm to individual specification sheet.





No	Item	Test Condition				R	equirements
2	Capacitance		*Shall ı	not e	exceed	the lim	its given in the detailed spec.
			NP0: Ca X7R,X5		•	≥1000; C	Cap<30pF,Q≥400+20C
			Rated vol.	D).F.≦		Exception of D.F. ≦
						≦3%	1206≧0.47µF
			≧100V	≦2	2.5%	≦5%	0805>0.1μF, 0603≧0.068μF, 1206>1μF; TT series
						≦3%	0201(50V); 0603≧0.047µF; 0805≧0.18µF;1206≧0.47µF
			≧50V	≦2	2.5%	≦5%	1210≧4.7µF
						≦10%	0402≧0.1µF; 0603≧1µF; 0805≧1µF; 1206≧4.7µF; 1210≧10µF TT series
			35V	≦3	3.5%	≦10%	0603≧1μF; 0805≥2.2μF; 1210≧10μF
						≦5%	0201≧0.01μF;0805≧1μF; 1210≧10μF
		Class I: NP0				≦7%	0603≧0.33μF; 1206≧4.7μF
		Cap≤1000pF 1.0±0.2Vrms, 1MHz±10% Cap>1000pF 1.0±0.2Vrms, 1KHz±10% Class II: X7R, X5R, X6S,Y5V	25V	≦3	3.5%	≦10%	0402≧0.10μF;0603≧0.47μF;0805≧2.2 μF; 1206≧6.8μF ; 1210≧22μF; TT series
		Class II. A7K, A5K, A6S, 75V Cap≤10µF, 1.0±0.2Vrms, 1kHz±10% **				≦12.5%	0402≧1µF
		Cap>10µF, 0.5±0.2Vrms, 120Hz±20%				≦5%	0201≧0.01μF; 0402≧0.033μF; 0805≧0.68μF;1206≧2.2μF;1210≧4.7μF
	Q/ D.F.	** Test condition: 0.5±0.2Vrms, 1KHz±10%	16V	≦\$	3.5%	≦10%	0201≥0.1μF; 0402≥0.47μF; 0603≥0.68μF;0805≥2.2μF; 1206≥4.7μF; 1210≥22μF; TT series
	(Dissipation Factor)	X7R: 0603≧225(10V), 0805=106(6.3V&10V)	10V	≦	≦5%	≦10%	0201≥0.012μF;0402≥0.33μF(0402/ X7R≥0.22μF); TT series 0603≥0.33μF; 0805≥2.2μF;1206≥2.2μF;1210≥22μF
		X5R: 01R5≧103, 0201≧224 (6.3V,10V),				≦15%	0201≧0.1μF; 0402≧1μF
		0402≧475 (6.3V), 0402≧225(10V), 0603=106 (6.3V,10V),	6.3V	≦	10%	≦15%	0201≥0.1μF;0402≥1μF;0603≥10μF; 0805≥4.7μF; 1206≥47μF :1210≥100μF; TT series
		TT18X ≧475(10V), TT15X series X6S:0201≧224 (6.3V),0402≧225				≦20%	0402≧2.2µF
		(6.3V),	4V	≦	15%	-	-
			Y5V:				
			Rate vol.		D.F.≦		Exception of D.F. ≦
			≥50\	/	5%	7%	0603≧0.1μF; 0805≧0.47μF; 1206≧4.7μF
			35V		7%	-	-
			25V		5%	7%	0402≥0.047μF;0603≥0.1μF; 0805≥0.33μF;1206≥1μF; 1210≥4.7μF
			250		570	9%	0402≧0.068μF; 0603≧0.47μF; 1206≧4.7μF; 1210≧22μF
			16V		7%	9%	0402≧0.068μF; 0603≧0.68μF
			(C<1µ	F)	, ,0	12.5%	0402≧0.22µF
			16V (C≧1.0µF)		9%	12.5%	0603≧2.2μF; 0805≧3.3μF; 1206≧10μF; 1210≧22μF; 1812≧47μF
			10V		12.5%	20%	0402≧0.47µF
			6.3√	<u></u>	20%	-	-





No	Item	Test Condition	Requirements			
4	Dielectric Strength	To apply voltage (≤100V) 250%. Duration: 1 to 5 sec. Charge and discharge current less than 50mA.	No evidence of damage or flash over duri	ng test.		
			10GΩ or RxC≧500Ω-F whichever is smaller. Class II (X7R, X5R, X6S, Y5V)			
			Rated voltage	Insulation Resistance		
			100V: X7R			
			50V:0603≥1μF;0805≥1μF;1206≥4.7μF; 1210≥4.7μF]		
			35V:0805≥2.2μF;1210≧10μF	Ī		
			25V:0402≥1µF;0603≥2.2µF;0805≥2.2µF; 1206≥10µF;1210≥10µF	10G or RxC≧100ΩF whichever is		
			16V:0402≥0.22µF;0603≥1µF;0805≥2.2µF; 1206≥10µF;1210≥47µF	smaller.		
5	Insulation Resistance	To apply rated voltage for max. 120 sec.	10V:0201≥47nF;0402≥0.47µF;0603≥0.47µF; 0805≥2.2µF; 1206≥4.7µF;1210≥47µF]		
			6.3V ; 4V	i i		
			All X6S items			
			50V: 0402≥0.1µF; 0603≥2.2µF; 0805≥10µF;1206≥10µF			
			35V: 0603≥1μF;]		
			25V: 0201≥0.1μF; 0402≥0.22μF; 0603≥10μF;1206≥22μF	RxC≧50 Ω-F.		
			16V: 0603≥10µF			
			10V: 0201>0.1μF; 0603≥10μF; 0805≥47μF			
			6.3V: 0201≥0.1µF; 1206≥10µF			
			4V:0603≥22μF; 0805≥47μF			
		With no electrical load.				
		T.C. Operating Temp	T.C. Capacitance Change			
		NPO -55~125°C at 25°C	NPO Within ±30ppm/°C			
6	Temperature	X7R -55~125°C at 25°C	X7R Within ±15%			
	Coefficient	X5R -55~ 85°C at 25°C	X5R Within ±15%			
		X6S -55~105°C at 25°C	X6S Within ±22%			
		Y5V -25~ 85°C at 20°C	Y5V Within +30%/-80%			
7	Adhesive Strength of Termination	Pressurizing force: 1N (0201) and 5N (≤0603) and 10N (>0603) * Test time: 10±1 sec.	No remarkable damage or removal of the terminations.			
8	Vibration Resistance	Vibration frequency: 10~55 Hz/min. Total amplitude: 1.5mm Test time: 6 hrs. (Two hrs each in three mutually perpendicular directions.) Measurement to be made after keeping at room temp. for 24±2 hrs.	No remarkable damage. Cap change and Q/D.F.: To meet initial sp	ec.		





No	Item		Test Condition		Requirements
9	Solderability		temperature: 235±5°C g time: 2±0.5 sec.		95% min. coverage of all metalized area.
10.	Bending Test	The middle part of substrate shall be pressurized by means of the pressurizing rod at a rate of about 1 mm per second until the deflection becomes 1 mm and then the pressure shall be maintained for 5±1 sec. Measurement to be made after keeping at room temp. for 24±2 hrs.			No remarkable damage. Cap change: NP0: within ±5% or 0.5pF whichever is larger X7R, X5R, X6S: within ±12.5% Y5V: within ±30% (This capacitance change means the change of capacitance under specified flexure of substrate from the capacitance measured before the test.)
11	Resistance to Soldering Heat	Dippin Prehea ute be eutecti Before only): then se Measu	temperature: 260±5°C g time: 10±1 sec ating: 120 to 150°C for 1 m fore immerse the capacitor c solder. initial measurement (Clas Perform 150+0/-10°C for 1 et for 24±2 hrs at room tem rement to be made after kin temp. for 24±2 hrs.	r in a s II hr and np.	No remarkable damage. Cap change: NP0: within ±2.5% or 0.25pF whichever is larger X7R, X5R, X6S: within ±7.5% Y5V: within ±20% Q/D.F., I.R. and dielectric strength: To meet initial requirements. 25% max. leaching on each edge.
			ct the five cycles according nperatures and time.	g to	
		Step	Temp. (°C)	(min.)	No. and the land of
		1	Min. operating temp. +0/-3	30±3	No remarkable damage. Cap change:
	Temperature	2	Room temp.	2~3	NP0: within ±2.5% or 0.25pF whichever is larger
12	2 Cycle	3	Max. operating temp. +3/-0	30±3	X7R, X5R, X6S: within ±7.5% Y5V: within ±20%
	-	4	Room temp.	2~3	Q/D.F., I.R. and dielectric strength: To meet initial
		only): I then so Measu	initial measurement (Clas Perform 150+0/-10°C for 1 et for 24±2 hrs at room ten Irement to be made after k In temp. for 24±2 hrs.	hr and np.	requirements.

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No	Item	Test Condition	Requirements					
			Cap cha NP0: wi X7R, X3 TT seriet **10V: 0 Y5V: ≥1 Q/D.F. v NP0: M Less tha	ange: ithin ±5% 5R, X6S es & C≥ 0603≧4. 0V, with value: ore than	: ≥10V** 1uF,withi 7µF;040 in ±30% 30pF Q Q≥200+	F whichever is larger ,within ±12.5%; ≤6.3V within ±25%; in ±25% 2≥1µF;0201≥0.1µF, within ±25%; ; ≤6.3V, within +30/-40% ≥350, 10pF≤C≤30pF, Q≥275+2.5C		
			Rated vol.	D.F.≦		Exception of D.F. ≦		
					≦6%	1206≧0.47μF		
			≧100V	≦3%	≦7.5%	0805>0.1μF, 0603≧0.068μF		
					≦6%	0201(50V); 0603≥0.047μF; 0805≥0.18μF;1206≥0.47μF		
			≧50V	≤3%	≦10%	1210≧4.7µF		
13	Humidity (Damp Heat)				≦20%	0402≧0.1μF; 0603≧1μF; 0805≧1μF;1206≧4.7μF; 1210≧10μF TT series		
	Steady State		35V	≦5%	≦20%	0603≧1μF; 0805≥2.2μF; 1210≧10μF		
				V ≦5%	≦10%	0201≧0.01μF;0805≧1μF; 1210≧10μF		
					≦14%	0603≧0.33μF; 1206≧4.7μF		
			25V		≦15%	0402≧0.10μF;0603≧0.47μF;0805≧2.2 μF; 1206≧6.8μF ; 1210≧22μF; TT series		
					≦20%	0402≧1µF		
					≦10%	0201≥0.01μF; 0402≥0.033μF; 0805≥0.68μF;1206≥2.2μF;1210≥4.7μF		
			16V	≦5%	≦15%	0201≥0.1μF; 0402≥0.47μF; 0603≥0.68μF;0805≥2.2μF; 1206≥4.7μF; 1210≥22μF; TT series		
			10V	≦7.5%	≦15%	0201≥0.012μF 0402≥0.33μF; 0603≥0.33μF; 0805≥2.2μF; 1206≥2.2μF; 1210≥22μF		
					≦20%	0201≧0.1μF; 0402≧1μF TT series		
			6.3V	≦15%	≦30%	0201≧0.1μF;0402≥1μF;0603≥10μF; 0805≥4.7μF; 1206≥47μF :1210≥100μF; TT series		
			4V	≦20%	-	-		

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No	Item	Test Condition			R	equirements		
			Y5V:					
			Rated vol.	D.F.≦		Exception	of D.F. ≦	
			≧50V	7.5%	10%	0603≧0.1µF; 080	5≧0.47μF; 1206≧4.7μF	
			35V	10%	-	-		
			25V	7.5%	10%	0402≧0.047µF;0 0805≧0.33µF;12	603≧0.1µF; 06≧1µF; 1210≧4.7µF	
			250	7.570	15%	0402≧0.068μF; 0603≧0.47μF; 1206≧4.7μF; 1210≧22μF		
			16V	10%	12.5%	0402≧0.068µF; 0	0603≧0.68μF	
			(C<1µF)	1070	20%	0402≧0.22μF		
			16V (C≧1.0µF)	(C≧1.0µF) 12.5%		0603≧2.2µF; 080 1210≧22µF; 181	05≧3.3μF; 1206≧10μF; 2≧47μF	
			10V	20%	30%	0402≧0.47μF		
			6.3V	30%	-	-		
13			*I.R.: ≥10V Class II (X			-F whichever is , Y5V)	s smaller.	
			Rated volt	age			Insulation Resistance	
			100V: X7R					
			50V: 0402≥ 1206≥4.7µ		F;0805≥1µF;			
			35V: 06032					
			25V:0402≥ 1206≥10µF			F;0805≥2.2μF;	1GΩ or RxC≧10 Ω-F	
			16V:0402≥ 1206≥10µF			ıF;0805≥2.2μF;	whichever is smaller.	
			I 	47nF;04		7μF;0603≥0.47		
			1206≥4.7µF;1210≥47µF					
			6.3V ; 4V		<u> </u>			
14	Humidity (Damp Heat) Load	Test temp.: 40±2°C Humidity: 90~95%RH Test time: 500+24/-0 hrs. To apply voltage: rated voltage. Before initial measurement (Class II only): To apply test voltage for 1hr at 40°C and then set for 24±2 hrs at room temp. Measurement to be made after keeping at room temp. for 24±2 hrs.	X7R, X5R, TT series & **10V: 060 Y5V: ≥10V Q/D.F. valu	je: % or 0.∄ X6S: ≥ & C≥ 1t 3≧4.7t , within ue:	75pF w :10V**, ıF,withiı ıF;0402 ±30%;	n ±25%	≦6.3V within ±25%; 0.1μF, within ±25%; +30/-40%	





No	Item	Test Condition			F	Requirements
			X7R, X	SR, X69	S:	
			Rated vol.	D.F.≦		Exception of D.F. ≦
					≦6%	1206≧0.47µF
			≧100V	≦3%	≦7.5%	0805>0.1µF, 0603≧0.068µF
					≦6%	0201(50V); 0603≧0.047µF; 0805≧0.18µF;1206≧0.47µF
			≧50V	≦3%	≦10%	1210≧4.7µF
				_676	≦20%	0402≧0.1μF; 0603≧1μF; 0805≧1μF;1206≧4.7μF; 1210≧10μF TT series
			35V	≦5%	≦20%	0603≧1μF; 0805≥2.2μF; 1210≧10μF
					≦10%	0201≧0.01μF;0805≧1μF; 1210≧10μF
					≦14%	0603≧0.33μF; 1206≧4.7μF
			25V	≦5%	≦15%	0402≧0.10μF;0603≧0.47μF;0805≧2.2 μF; 1206≧6.8μF ; 1210≧22μF; TT series
					≦20%	0402≧1µF
		leat)			≦10%	0201≧0.01µF; 0402≧0.033µF; 0805≧0.68µF;1206≧2.2µF;1210≧4.7µF
	Humidity		16V	≦5%	≦15%	0201≧0.1μF; 0402≧0.47μF; 0603≧0.68μF; 0805≧2.2μF; 1206≧4.7μF; 1210≧22μF; TT series
14	(Damp Heat) Load		10V	≦7.5%	≦15%	0201≧0.012µF 0402≧0.33µF; (0402/ X7R≥0.22µF); 0603≧0.33µF; 0805≧2.2µF; 1206≧2.2µF; 1210≧22µF
					≦20%	0201≧0.1μF; 0402≧1μF; TT series
			6.3V	≦15%	≦30%	0201≥0.1μF;0402≥1μF;0603≥10μF; 0805≥4.7μF; 1206≥47μF :1210≥100μF; TT series
			4V	≦20%	-	-
			Y5V:			
			Rated vol.	D.F	.≦	Exception of D.F. ≦
			≧50V	7.5	% 10%	0603≧0.1μF; 0805≧0.47μF; 1206≧4.7μF
			35V	10	% -	-
			25V	7.5	10%	0402≧0.047μF;0603≧0.1μF; 0805≧0.33μF;1206≧1μF; 1210≧4.7μF
			250	7.5	15%	0402≧0.068μF; 0603≧0.47μF; 1206≧4.7μF; 1210≧22μF
			16V	. 10	12.5%	0 0402≧0.068μF; 0603≧0.68μF
			(C<1µF) 10	20%	0402≧0.22µF
			16V (C≧1.0µ	F) 12.	5% 20%	0603≧2.2μF; 0805≧3.3μF; 1206≧10μF; 1210≧22μF; 1812≧47μF
			10V	20	% 30%	0402≧0.47µF
			6.3V	30	% -	-





No	Item	Test Condition	Requirements	
			*I.R.: ≥10V, 500MΩ or 25 Ω-F whicheve Class II (X7R, X5R, X6S, Y5V)	is smaller.
			Rated voltage	Insulation Resistance
			100V: X7R	
	Humidity		50V: 0402≥0.1μF;0603≥1μF;0805≥1μF; 1206≥4.7μF;1210≥4.7μF	
14	(Damp Heat)		35V: 0603≥1µF; 0805≥2.2µF;1210≥10µF	
	Load		25V:0402≥1µF;0603≥2.2µF;0805≥2.2µF; 1206≥10µF;1210≥10µF	500GΩ or RxC≧5 Ω-F whichever is
			16V:0402≥0.22µF;0603≥1µF;0805≥2.2µF; 1206≥10µF;1210≥47µF	smaller.
			10V:0201≥47nF;0402≥0.47μF;0603≥0.47 μF;0805≥2.2μF; 1206≥4.7μF;1210≥47μF	
			6.3V; 4V; TT series; All X6S items	
15.	High Temperature Load (Endurance)	*Test temp.: NP0, X7R/X7E: 125±3°C X6S: 105±3°C X5R, Y5V: 85±3°C *Test time: 1000+24/-0 hrs. *To apply voltage: 1) ≦% of rated voltage. 2) 10V≦Ur<500V: 200% of rated voltage. 3) 500V: 150% of rated voltage. 4) Ur≧630V: 120% of rated voltage.	No remarkable damage. Cap change: NP0: ±3.0% or ±0.3pF whichever is larg X7R, X5R, X6S: ≥10V**,within ±12.5%; TT series & C≥ 1uF,within ±25% **10V: 0603≥4.7µF;0402≥1µF;0201≥0 Y5V: ≥10V, within ±30%; ≤6.3V, within + Q/D.F. value: NP0: More than 30pF, Q≥350 10pF≤C<30pF, Q≥275+2.5C Less than 10pF, Q≥200+10C	≦6.3V within ±25%; .1µF, within ±25%;





		Size 0201 0402	% of rated ve. Dielectric X5R/X7R/ X6S X5R/X7R/ X6S	voltage for Rated voltage 6.3V,10V	Capaci- tance range		X7R, X5 Rated vol. ≧100V	D.F.≦	≦6%	Exception of D.F. ≦ 1206≧0.47µF
		Size 0201 0402	Dielectric X5R/X7R/ X6S X5R/X7R/	Rated voltage	Capaci- tance range		vol.		<6%	· .
		Size 0201 0402	Dielectric X5R/X7R/ X6S X5R/X7R/	Rated voltage	Capaci- tance range		≧100V	~00/	<6%	1206>0.47uE
		0201	X5R/X7R/ X6S X5R/X7R/	voltage	tance range		= 100 V		=0 /0	1200=0.7/μι
		0201	X5R/X7R/ X6S X5R/X7R/	voltage	range	HI		≦3%	≦7.5%	0805>0.1μF, 0603≧0.068μF
		0402	X6S X5R/X7R/	6.3V,10V	range				≦6%	0201(50V); 0603≧0.047μF; 0805≧0.18μF;1206≧0.47μF
			X5R/X7R/		C≦0.1µF		≥50V	≦3%	≦10%	1210≧4.7μF
		0000		6.3V,10V	C≧1.0µF				≦20%	0402≥0.1μF; 0603≥1μF; 0805≥1μF;1206≥4.7μF; 1210≥10μF TT series
		0000		4V	C≧22µF		35V	≦5%	≦20%	0603≧1μF; 0805≥2.2μF; 1210≧10μF
		0603	X5R/X7R/ X6S	6.3V,10V	C≧4.7µF		İ		≦10%	0201≧0.01μF;0805≧1μF; 1210≧10μF
				35V	C≧1.0µF				≦14%	0603≧0.33μF; 1206≧4.7μF
		0805	X5R/X7R/ X6S	4V 6.3V	C≧47µF		25V	≦5%	≦15%	0402≧0.10μF;0603≧0.47μF;0805≧2.2 μF; 1206≧6.8μF ; 1210≧22μF; TT series
			X5R/X7R/	6.3V	C≧22µF		i i		≦20%	0402≧1µF
		1206	NP0	3,000V	C≧47μF C≧1.5pF				≦10%	0201≧0.01μF; 0402≧0.033μF; 0805≧0.68μF;1206≧2.2μF;1210≧4.7μF
	High	TT18	Y5V Y5V	6.3V,10 6.3V	C≧2.2μF C≧10μF		16V	≦5%	≦5% ≤15%	0201≥0.1μF; 0402≥0.47μF; 0603≥0.68μF;0805≥2.2μF; 1206≥4.7μF; 1210≥22μF; TT series
15	Temperature Load	. ,	Y5V % of rated	6.3V voltage fo	C≧22μF or below		10V	≦7.5%	≦15%	0201≥0.012μF 0402≥0.33μF; 0603≥0.33μF; 0805≥2.2μF; 1206≥2.2μF; 1210≥22μF;
'	(Endurance)	ran	ge.						≦20%	0201≧0.1μF; 0402≧1μF
		Size	Dielectric	Rated voltage	Capaci- tance range		6.3V	≦15%	≦30%	0201≥0.1μF;0402≥1μF;0603≥10μF; 0805≥4.7μF; 1206≥47μF :1210≥100μF; TT series
		0201	X5R/X7R/ X6S	16V	C≧0.1µF		4V	≦20%	-	-
			X5R/X7R/	50V	C≧0.1µF		Y5V:	· · · · ·		
		0402	X6S	10V~25V	C≧0.22µF		Rated vol.	D.F.≘	=	Exception of D.F. ≦
			Y5V	16V	C≧0.47µF		≥50V	7.5%	10%	0603≧0.1μF; 0805≧0.47μF; 1206≧4.7μF
		0603	X5R/X7R/ X6S	10V,50V	C≧1.0µF		35V	10%	-	-
			Y5V	16V	C≧2.2µF				10%	0402≧0.047μF;0603≧0.1μF; 0805≧0.33μF;1206≧1μF; 1210≧4.7μF
			X5R/X7R/ X6S	10~50V	C≧4.7µF		25V	7.5%	15%	0402≥0.068µF; 0603≥0.47µF; 1206≥4.7µF; 1210≥22µF
		0805	X7R	50V	C≧2.2µF		16V	+	12.5%	0402≧0.068µF; 0603≧0.68µF
			7	100V	C≧0.47µF		(C<1µF) 10%	20%	0402≧0.22µF
		2220	Y5V X7R	16V 100V	C≧4.7μF C≧6.8μF		16V (C≧1.0µI	12.59	6 20%	 0603≥2.2μF; 0805≥3.3μF; 1206≥10μF; 1210≥22μF; 1812≥47μF
		2220 Λ/R 1000 C≦0.8μF			10V	20%	30%	0402≧0.47μF		
							6.3V	30%	-	-

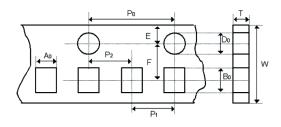




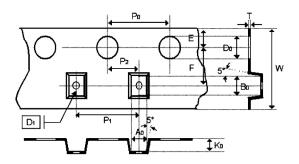
No	Item	Test Condition	Requirements				
		*Before initial measurement (Class II only): To apply test voltage for 1hr at test temp. and	*I.R.: ≥10V, 1GΩ or 50 Ω-F whichever is smaller. Class II (X7R, X5R, X6S, Y5V)				
		then set for 24±2 hrs at room temp.	Rated voltage	Insulation Resistance			
		*Measurement to be made after keeping at room temp. for 24±2 hrs	100V: X7R				
	High Temperature		50V: 0402≥0.1μF;0603≥1μF;0805≥1μF; 1206≥4.7μF;1210≥4.7μF				
15			35V: 0603≥1µF; 0805≥2.2µF;1210≥10µF				
	(Endurance		25V:0402≥1µF;0603≥2.2µF;0805≥2.2µF; 1206≥10µF;1210≥10µF	1GΩ or RxC≧10 Ω-F whichever is			
			16V:0402≥0.22µF;0603≥1µF;0805≥2.2µF; 1206≥10µF;1210≥47µF	smaller.			
			10V:0201≥47nF;0402≥0.47µF;0603≥0.47 µF;0805≥2.2µF;				
		Temperature at Product (°C)	6.3V; 4V; TT series; All X6S items				

Appendixes

Tape & Reel Dimensions



The dimension of paper tape



The dimension of plastic tape

Size	0201	04	02	0603		0805			1206			1210	,		1812	
Thick- ness	L	N	E	S, X	Α	В	C, D, I	В	C, J, D	G,P	C, D	G, K	М	D, K	М	U
A ₀	0.38±0.05	0.62±0.05	0.7±0.1	1.02±0.05	1.5±0.1	1.5±0.1	<1.57	2±0.1	<1.85	<1.95	<2.97	<2.97	<2.97	<3.81	<3.81	<3.9
В0	0.68±0.05	1.12±0.05	1.2±0.1	1.8±0.05	2.3±0.1	2.3±0.1	<2.40	3.5±0.1	<3.46	<3.67	<3.73	<3.73	<3.73	<5.3	<5.3	<5.3
Т	0.42±0.05	0.6±0.05	0.7±0.1	0.95±0.05	0.75±0.05	0.95±0.05	0.23±0.05	0.95±0.05	0.23±0.05	0.23±0.05	0.23±0.05	0.23±0.05	0.23±0.05	0.25±0.05	0.25±0.05	0.25±0.05
К0	-	-	-	-	-	-	<2.5	-	<2.5	<2.5	<2.5	<2.5	<3	<2.5	<3	<3.5
W	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	12±0.2	12±0.2	12±0.2
P ₀	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1
10xP ₀	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.2
P1	2±0.05	2±0.05	2±0.05	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.10	4±0.1	8±0.1	8±0.1	8±0.1
P ₂	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05
D ₀	1.55±0.05	1.55±0.05	1.55±0.05	1.55±0.05	1.55±0.05	1.55±0.05	1.5±0.05	1.5±0.05	1.5±0.05	1.5±0.05	1.5±0.05	1.5±0.05	1.5±0.05	1.5±0.05	1.5±0.05	1.5±0.1
D ₁	-	-	-	-	-	-	1±0.1	-	1±0.1	1±0.1	1±0.1	1±0.1	1±0.1	1.5±0.1	1.5±0.1	1.5±0.1
E	1.75±0.05	1.75±0.05	1.75±0.05	1.75±0.05	1.75±0.05	1.75±0.05	1.75±0.1	1.75±0.1	1.75±0.1	1.75±0.1	1.75±0.1	1.75±0.1	1.75±0.1	1.75±0.1	1.75±0.1	1.75±0.1
F	3.50±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	5.5±0.05	5.5±0.05	5.5±0.05

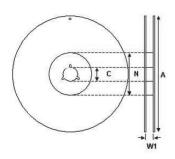
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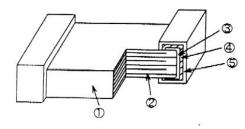




Size	0201, 0402	0201, 0402, 0603, 0805, 1206, 1210						
Reel size	7"	10"	13"	7"				
С	13 +0.5/-0.2	13 +0.5/-0.2	13 +0.5/-0.2	13 +0.5/-0.2				
W1	8.4 +1.5/-0	8.4+1.5/-0	8.4 +1.5/-0	12.4+2.0/-0				
Α	178 ±0.1	250 ±1	330 ±1	178 ±0.1				
N	60 +1/-0	100 ±1	100 ±1	60 +1/-0				

The dimension of reel

Constructions:



No.	Na	me	NPO, X7R, X5R, X6S, Y5V
1	Ceramic	material	BaTiO₃ based
2	Inner el	ectrode	Ni
3		Inner layer	Cu
4	Termination	Middle layer	Ni
5		Outer layer	Sn

Storage and handling conditions

- (1) To store products at 5°C to 40°C ambient temperature and 20 to 70%. related humidity conditions.
- (2) The product is recommended to be used within one year after shipment. Check solderability in case of shelf life extension is needed.

Cautions:

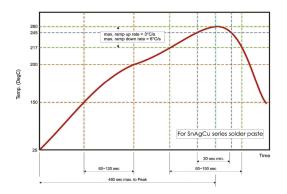
- a. The corrosive gas reacts on the terminal electrodes of capacitors, and results in the poor solderability. Do not store the capacitors in the ambience of corrosive gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas etc.)
- b. In corrosive atmosphere, solderability might be degraded, and silver migration might occur to cause low reliability.
- c. Due to the dewing by rapid humidity change, or the photochemical change of the terminal electrode by direct sunlight, the solderability and electrical performance may deteriorate. Do not store capacitors under direct sunlight or dewing condition. To store products on the shelf and avoid exposure to moisture.



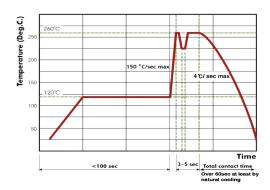


Recommended Soldering Conditions:

The lead-free termination MLCCs are not only to be used on SMT against lead-free solder paste, but also suitable against lead-containing solder paste. If the optimized solder joint is requested, increasing soldering time, temperature and concentration of N_2 within oven are recommended.



Recommended reflow soldering profile for SMT process with SnAgCu series solder paste.



Recommended wave soldering profile for SMT process with SnAgCu series solder.

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